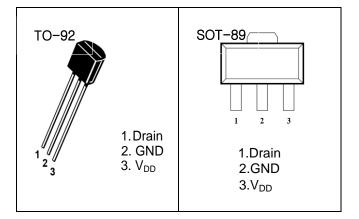
HIGH-VOLTAGE LED DRIVER WITH BUILD-IN MOSFET SWITCH

IL9921/22/23

FEATURES

- Operating temperature range -40 ..+85 °C
- ON-resistance of the MOSFET switch 210 Ohm for ambient temperature 25 °C
- OFF-state breakdown voltage of the MOSFET switch not less 500 V for Ambient temperature 25 °C.



ORDERING INFORMATION

Device	Operating Temperature Range	Package	Packing
IL9921LF, IL9922LF, IL9923LF		TO-92	Таре
IL9921PT, IL9922PT, IL9923PT	T _A = - 40 + 85 °C	SOT-89	Tape & Reel

DESCRIPTION

IL9921, IL9922, IL9923 are high-voltage LED driver control ICs with build-in MOSFET switch and purposed for LED lighting control.

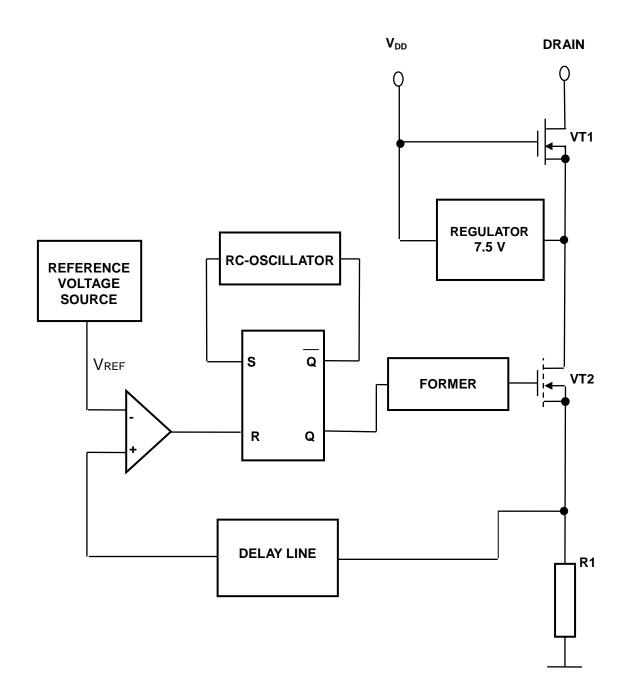
They allow efficient operation of LED strings from voltage sources ranging up to 400VDC. The IL9921/22 includes an internal high-voltage switching MOSFET controlled with fixed off-time TOFF of approximately 10µs. The LED string is driven at constant current, thus providing constant light output and enhanced reliability. The output current is internally fixed at 20mA for IL9921, 50mA for IL9922 and 30mA for IL9923. The peak current control scheme provides good regulation of the output current throughout the universal AC line voltage range of 85 to 264V AC or DC input voltage of 20 to 400V.

PIN DESCRIPTION

Pin No	Symbol	Description		
1	Drain	This is a drain terminal of the output switching MOSFET and a linear Regulator input.		
2	GND	This is a common connection for all circuits		
X V		This is a power supply pin for all control circuits. Bypass this pin with a 0.1uF low impedance capacitor.		



BLOCK DIAGRAM





ABSOLUTE MAXIMUM RATINGS

Symbol	Baramatar	Li	Unit	
	Parameter	Min	Max	Unit
V _{IN}	Input voltage	-0.3	420	V
V _{DD}	Low-voltage (control) part of IC supply voltage	-0.3	10	V

* Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.

Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATION RANGE

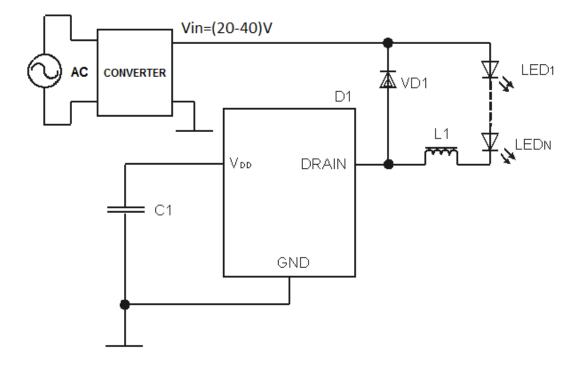
Symbol	Parameter	Lir	Unit		
	Symbol	Farameter	Min	Max	Unit
	V _{IN}	Input voltage	20	400	V

ELECTRICAL CHARACTERISTICS

			Limit		Ambient	
Symbol	Parameter	Test Condition	Min	Max	temperature, °C	Unit
V _{DDR}	Regulator output voltage	V _{IN} = (20- 400)V	(20- 400)V 5.5 9.0			V
I _{DD}	Low-voltage (control) part of IC consumption current	V _{DD} = 9,5 V V _{IN} = 40 V	-	350		uA
R _{ON}	ON-resistance of the switch (DRAIN pin)	$V_{DD} = V_{DDR}$ $I_{DRAIN} = 20 \text{ mA}$	-	210		Ohm
V _{UVLO}	Undervoltage threshold (Low-voltage part of IC)	$V_{DD} = V_{UVLO}$ $I_{DRAIN} = 20 \text{ mA}$	4.0	V _{DDR} – 0.3		V
I _{SAT}	MOSFET saturation current (DRAIN pin)	V_{DD} = V_{DDR} V_{SAT} = 50 V	100	-	25 ± 10	mA
V_{BR}	OFF-state breakdown voltage of the MOSFET switch (DRAIN pin)	$V_{DD} = V_{DDR}$ $I_{DRAIN} = 1 \text{ mA}$	500	-		V
I _{TH}	Threshold current IL9921 IL9922 IL9923	$V_{DD} = V_{DDR}$ $V_{IN} = 50 V$	20.5 52.0 30.8	25.5 63.0 38.2	25 ± 10 -40 85	mA
T _{OFF}	OFF time (DRAIN pin)		8.0	13.0		us
T _{ON}	Minimum ON-time of the switch (DRAIN pin)	$V_{DD} = V_{DDR}$	-	650	25 ± 10	ns
T _{BLANK}	Leading Edge Blanking Delay	V _{IN} = 50 V	200	400		ns



RECOMMENDED APPLICATION DIAGRAM



AC – AC supply voltage source C1 – capacitor C= $0.1 \mu F \pm 10 \%$ D1 – microcircuit L1 – inductor (coil)

,

Inductor feature L, mH, is calculated by formula:

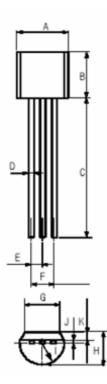
$$L = \frac{15 \cdot N \cdot U_F}{dI_O}$$

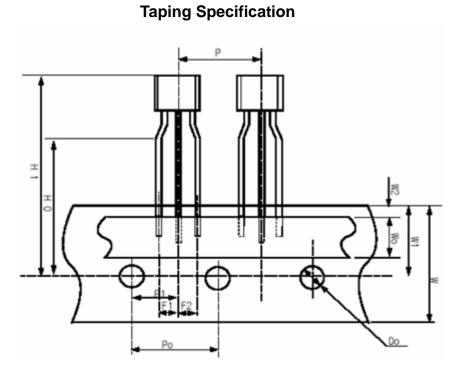
- N Quantity of diodes in LED string, pcs.; V_F – LED forward voltage for nominal current, V;
- dI₀ LED circuit permissible current ripple, mA
- $LED_1 LED_N LEDs$ (light emitting diodes) with nominal current:
 - 20 mA for IL9921 application;
 - 50 mA for IL9922 application;
 - 30 mA for IL9923 application
- VD1 high-voltage diode with breakdown voltage not less 500V and forward current:
 - not less 25.5 mA for IL9921 application;
 - not less 63.0 mA for IL9922 application;
 - not less 38.2 mA for IL9923 application



PACKAGE DIMENSION

TO-92

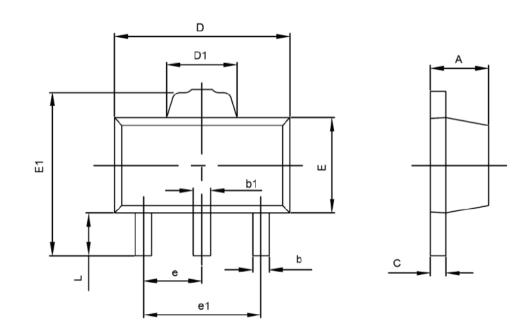




Package Dimension(unit:mm)				Taping Dimension(unit:mm)			
Symbol	Min	Тур	Max	Symbol	Min	Тур	Max
A	4.43	4.58	4.83	Р	12.2	12.7	13.2
В	4.38	4.58	4.78	PO	12.5	12.7	12.9
с	14.07	14.47	14.87	P1	5.85	6.35	6.85
D	0.36	0.46	0.56	F1,F2	2.4	2.5	2.9
E	1.07	1.27	1.47	w	17.5	18.0	19.0
F	2.34	2.54	2.74	wo	5.5	6.0	6.5
G	3.40	3.60	3.80	W1	8.5	9.0	9.5
н		-	3.86	W2		-	1.0
I		[R2.29]		но	15.5	16.0	16.5
J	0.33	0.38	0.39	H1		-	27.0
к	0.92	1.02	1.12	DO	3.8	4.0	4.2



SOT-89-3L



Countral	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1.400	1.600	0.055	0.063	
b	0.320	0.520	0.013	0.020	
b1	0.360	0.560	0.014	0.022	
c	0.350	0.440	0.014	0.017	
D	4.400	4.600	0.173	0.181	
D1	1.400	1.800	0.055	0.071	
E	2.300	2.600	0.091	0.102	
E1	3.940	4.250	0.155	0.167	
e	1.500	DTYP	0.06	0TYP	
e1	2.900	3.100	0.114	0.122	
L	0.900	1.100	0.035	0.043	

